

# Si photodiode

S10917-35GT

# RGB color sensor integrated in small and thin package

The S10917-35GT is a compact color sensor with a 3-channel photodiode mounted in one package, and sensitive to red ( $\lambda$ =590 to 680 nm), green ( $\lambda$ =470 to 600 nm) and blue ( $\lambda$ =390 to 530 nm) light. An infrared-cut filter is formed on the photosensitive area. This color sensor achieves superior cost performance and is suitable for monitoring brightness of RGB-LED backlight LCD in hand-held devices such as cell phones.

#### Features

- Infrared-cut filter formed on photosensitive area
- Superior cost performance
- Small, thin package: 3.0 × 1.6 × 1.0 <sup>t</sup>mm
- 3-channel (RGB) Si photodiode
- Photosensitive area: 1 × 1 mm/3-segment (RGB)
- RoHS-compatible
- Surface mount type

#### Applications

- Portable or mobile equipment
- RGB-LED type LCD backlight monitors
- Detectors for various light sources
- Color detection

#### Absolute maximum ratings

Parameter	Symbol	Value	Unit
Reverse voltage	Vr max	10	V
Operating temperature	Topr	-25 to +85	°C
Storage temperature	Tstg	-40 to +85	°C

Note: Exceeding the absolute maximum ratings even momentarily may cause a drop in product quality. Always be sure to use the product within the absolute maximum ratings.

#### Electrical and optical characteristics (Ta=25 °C, per element)

Parameter	Symbol	Condition	Min.	Тур.	Max.	Unit			
		Blue	-	390 to 530	-	nm			
Spectral response range	λ	Green	-	470 to 600	-				
		Red	-	590 to 680	-	]			
		Blue	-	460	-				
Peak sensitivity wavelength	λр	Green	-	nm					
		Red	-	620	-				
	S	Blue $(\lambda = \lambda p)$	0.15	0.2	0.25	A/W			
Photosensitivity		Green ( $\lambda = \lambda p$ )	0.18	0.23	0.28				
		Red ( $\lambda = \lambda p$ )	0.12	0.17	0.22	]			
Dark current	ID	VR=1 V, all elements	-	1	50	рА			
Temperature coefficient of ID	TCID		-	1.12	-	times/°C			
Rise time	tr	VR=0 V, RL=1 kΩ, 10 to 90%	-	0.1	0.5	μs			
Terminal capacitance	nal capacitance Ct VR=0 V, f=10 kHz		5	12	25	pF			



**Linearity** 



# Dark current vs. reverse voltage



# - Terminal capacitance vs. reverse voltage



KSPDB0253EA

## Dimensional outline (uint: mm)



## Measured example of temperature profile with our hot-air reflow oven for product testing

This product supports lead-free soldering. After unpacking, store it in an environment at a temperature of 30 °C or less and a humidity of 60% or less, and perform soldering within 24 hours.





KSPDB0139EA



Type no.	Туре	Photosensitive area (mm)	Package (mm)	Peak wa (	sensitivity velength (nm)	Photosensitivity				Photo			
			$4 \times 4.8 \times 1.8^{t}$	В	460	В		0.18 (A/W)	) [λ:	=46	0 nm]		
S9032-02	Photodiode	φ2.0	6 pin	G	540	G		0.23 (A/W)	) [λ=	=54	0 nm]		
			(filter 0.75')	R	620	R		0.16 (A/W)	) [λ=620 nm]				
			$3 \times 4 \times 1.3^{t}$	В	460	В		0.18 (A/W)	[λ=460 nm]		0 nm]		
S9702 Pho	Photodiode	1.0 × 1.0	4 pin (filter 0.75 <sup>t</sup> )	G	540	G		0.23 (A/W)	) [λ:	=54	0 nm]		
				R	620	R		0.16 (A/W)	) [λ:	=62	0 nm]		
S10917-35GT Photodiod			$3 \times 1.6 \times 1.0^{t}$ COB (on-chip filter)	В	460	В		0.2 (A/W)	[λ=	460	nm]		
	Photodiode	1.0 × 1.0		G	540	G		0.23 (A/W)	) [λ:	=54	0 nm]		
				R	620	R		0.17 (A/W)	) [λ:	=62			
S10942-01CT Photodiode		e 1.0 × 1.0	$3 \times 1.6 \times 1.0^{t}$	*		В		0.21 (A/W)					
	Photodiode		COB (on-chip filter)			G		0.25 (A/W)					
						R	0.45 (A/W) [λ=640 nm]						
	Digital		$\begin{array}{c} 4 \times 4.8 \times 1.8^{t} \\ 6 \text{ pin} \end{array}$	В	465	>	В	0.21 (LSB/ <i>lx</i> )	-C	В	1.9 (LSB/ <i>lx</i> )		
S9706 Digital photo I(	photo IC	1.2 × 1.2		G	540	Lov	G	0.45 (LSB/lx)	High	G	4.1 (LSB/ <i>lx</i> )		
	photo ie		(filter 0.75 <sup>t</sup> )	R	615		R	0.64 (LSB/lx)		R	5.8 (LSB/ <i>lx</i> )		
S11012-01CR Digital photo IC		$3.43 \times 3.8 \times 1.6^{t}$			_	В	0.3 (LSB/ <i>lx</i> )	~	В	2.6 (LSB/ <i>lx</i> )	Z and a local diversity of the		
	nhoto IC	bloto IC	COB (on-chip filter)		* 0	٥ ٥	G	0.6 (LSB/ <i>lx</i> )	High	G	5.3 (LSB/ <i>lx</i> )		
	prioto ic						R	1.4 (LSB/ <i>lx</i> )		R	12.9 (LSB/lx)		
S11059-02DT cor /-03DS	I <sup>2</sup> C compatible		$3 \times 4.2 \times 1.3^{t}$ 10 pin	В	460	460 530 615	В	4.4 (count/ <i>lx</i> )	High	В	44.8 (count/lx)	3	
		0.56 × 1.22		G	530		G	8.3 (count/lx)		G	85.0 (count/lx)		
	color	0.30 × 1.22		R	615		R	11.2 (count/ <i>lx</i> )		R	117.0 (count/lx)		
	sensor	sensor			IR	855		IR	3.0 (count/ $lx$ )	1	IR	30.0 (count/ $lx$ )	

#### Lineup of RGB color sensors

\* Refer to the spectral response of each product's datasheet.

#### Related information

www.hamamatsu.com/sp/ssd/doc\_en.html

- Precautions
  - Disclaimer
  - · Metal, ceramic, Plastic Package products
  - · Surface mount type products

Information described in this material is current as of February, 2016.

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